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## BIB DATA SHEET

CONFIRMATION NO. 2196

<b>SERIAL NUMBER</b> 10/777,025	<b>FILING or 371(c) DATE</b> 02/11/2004 <b>RULE</b>	<b>CLASS</b> <del>700</del> 714	<b>GROUP ART UNIT</b> 2117	<b>ATTORNEY DOCKET NO.</b> 1520.013447 (INFN/LL0056)		
<b>APPLICANTS</b> Mario Di Ronza, Munchen, GERMANY; Yannick Martelloni, Poing, GERMANY; <b>** CONTINUING DATA *****</b> <b>** FOREIGN APPLICATIONS *****</b> EUROPEAN PATENT OFFICE (EPO) 03 002 698.3 02/12/2003 <b>** IF REQUIRED, FOREIGN FILING LICENSE GRANTED **</b> 05/10/2004						
Foreign Priority claimed <input checked="" type="checkbox"/> Yes <input type="checkbox"/> No 35 USC 119(a-d) conditions met <input checked="" type="checkbox"/> Yes <input type="checkbox"/> No Verified and Acknowledged <u>/CYNTHIA H BRITT/</u> Examiner's Signature		<input type="checkbox"/> Met after Allowance Initials	<b>STATE OR COUNTRY</b> GERMANY	<b>SHEETS DRAWINGS</b> 8	<b>TOTAL CLAIMS</b> 33	<b>INDEPENDENT CLAIMS</b> 4
<b>ADDRESS</b> PATTERSON & SHERIDAN, LLP Gero McClellan / Qimonda 3040 POST OAK BLVD., SUITE 1500 HOUSTON, TX 77056 UNITED STATES						
<b>TITLE</b> Memory built-in self repair (MBISR) circuits/devices and method for repairing a memory comprising a memory built-in self repair (MBISR) structure						
<b>FILING FEE RECEIVED</b> 1960	FEES: Authority has been given in Paper No. _____ to charge/credit DEPOSIT ACCOUNT No. _____ for following:		<input type="checkbox"/> All Fees <input type="checkbox"/> 1.16 Fees (Filing) <input type="checkbox"/> 1.17 Fees (Processing Ext. of time) <input type="checkbox"/> 1.18 Fees (Issue) <input type="checkbox"/> Other _____ <input type="checkbox"/> Credit			